INTEGRATED CIRCUITS



Product data Supersedes data of 1994 Aug 31 File under Integrated Circuits, IC11 Handbook 2001 Aug 03





LM219/LM319

DESCRIPTION

The LM319 series are precision high-speed dual comparators fabricated on a single monolithic chip. They are designed to operate over a wide range of supply voltages down to a single 5 V logic supply and ground. Further, they have higher gain and lower input currents than devices like the μ A710. The uncommitted collector of the output stage makes the LM319 compatible with RTL, DTL, and TTL as well as capable of driving lamps and relays at currents up to 25 mA.

Although designed primarily for applications requiring operation from digital logic supplies, the LM319 series are fully specified for power supplies up to ± 15 V. It features faster response than the LM111 at the expense of higher power dissipation. However, the high-speed, wide operating voltage range and low package count make the LM319 much more versatile than older devices like the μ A711.

FEATURES

- Two independent comparators
- Operates from a single 5 V supply
- Typically 80 ns response time at ±15 V
- Minimum fanout of 3 (each side)
- Maximum input current of 1 µA over temperature
- Inputs and outputs can be isolated from system ground
- High common-mode slew rate

EQUIVALENT SCHEMATIC





Figure 1. Pin Configuration



Figure 2. Equivalent Schematic

LM219/LM319

Product data

ORDERING INFORMATION

DESCRIPTION	TEMPERATURE RANGE	ORDER CODE	DWG #
14-Pin Plastic Small Outline (SO) Package	–25 °C to +85 °C	LM219D	SOT108-1
14-Pin Plastic Small Outline (SO) Package	0 °C to +70 °C	LM319D	SOT108-1
14-Pin Plastic Dual In-Line Package (DIP)	0 °C to +70 °C	LM319N	SOT27-1

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNIT
Vs	Total supply voltage	36	V
	Output to negative supply voltage	36	V
	Ground to negative supply voltage	25	V
	Ground to positive supply voltage	18	V
	Differential input voltage	±5	V
V _{IN}	Input voltage ¹	±15	V
	Maximum power dissipation, T _{amb} = 25 °C (still-air) ² N package D package	1420 1040	mW mW
	Output short-circuit duration	10	S
T _{amb}	Operating temperature range LM219 LM319	-25 to +85 0 to +70	°C
T _{stg}	Storage temperature range	-65 to +150	°C
T _{sld}	Lead soldering temperature (10 sec max)	230	°C

NOTES:

1. For supply voltages less than \pm 15 V, the absolute maximum rating is equal to the supply voltage.

Derate above 25 °C, at the following rates: N package at 11.4 mW/°C

D package at 8.3 mW/°C

DC ELECTRICAL CHARACTERISTICS

 $V_{S} = \pm 15 \text{ V}; -25 \text{ °C} \leq T_{amb} \leq +85 \text{ °C} \text{ for LM219}, 0 \text{ °C} \leq T_{amb} \leq +70 \text{ °C for LM319}, unless otherwise specified.$

SYMPOL	DADAMETED	TEST CONDITIONS		LM219		LM319				
STWIDUL			Min	Тур	Max	Min	Тур	Max	UNIT	
V _{OS}	Input offset voltage ^{1, 2}	R _S ≤ 5 kΩ; T _{amb} = 25 °C Over temp.		0.7	4.0 7		2.0	8.0 10	mV	
I _{OS}	Input offset current ^{1, 2}	T _{amb} = 25 °C Over temp.		30	75 100		80	200 300	nA	
Ι _Β	Input bias current ¹	T _{amb} = 25 °C Over temp.		150	500 1000		250	1000 1200	nA nA	
A _V	Voltage gain	T _{amb} = 25 °C	8	40		8	40		V/mV	
V _{OL}	Saturation voltage	$V_{IN} \le -10 \text{ mV}; I_{OUT} = 25 \text{ mA};$ $T_{amb} = 25 ^{\circ}C; V+ ≥ 4.5 V; V- = 0 V$		0.75	1.5		0.75	1.5	V	
		$V_{IN} \leq -10 \text{ mV}; I_{OUT} = 3.2 \text{ mA}$		0.3	0.6		0.3	0.4		
I _{OH}	Output leakage current	V− = 0 V; V _{IN} ≥ 10 mV V _{OUT} = 35 V; T _{amb} = 25 °C		0.2	10		0.2	10	μΑ	
V _{IN}	Input voltage range	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		±13	3	V				
V _{ID}	Differential input voltage				±5			±5	V	
l+	Positive supply current	V+=5V; V- = 0 V; T_{amb} = 25 °C		4.3			4.3		mA	
l+	Positive supply current	$V_S = \pm 15$ V; $T_{amb} = 25$ °C		8.0	12.5		8.0	12.5	mA	
I–	Negative supply current	$V_{S} = \pm 15 \text{ V}; \text{ T}_{amb} = 25 ^{\circ}\text{C}$		3.0	5.0		3.0	5.0	mA	

NOTES:

1. V_{OS} , I_{OS} and I_B specifications apply for a supply voltage range of $V_S = \pm 15$ V down to a single 5 V supply. 2. The offset voltages and offset currents given are the maximum values required to drive the output to within 1 V of either supply with a 1 mA load. Thus these parameters define an error band and take into account the worst case effects of voltage gain and input impedance.

LM219/LM319

AC ELECTRICAL CHARACTERISTICS

SYMPOL	DADAMETED	TEST CONDITIONS				
STMBOL	FARAMETER	TEST CONDITIONS	Min	Тур	Max	UNIT
t _R	Response time ¹	$V_S = \pm 15 \text{ V}; \text{ T}_{amb} = 25 \text{ °C}$ R _L = 500 Ω (see test figure)		80		ns

NOTE:

1. The response time specified is for a 100 mV step with 5 mV overdrive.

TEST CIRCUIT



Figure 3. Test Circuit

LM219/LM319

Dual voltage comparator

TYPICAL PERFORMANCE CHARACTERISTICS



Figure 4. Typical Performance Characteristics

LM219/LM319

TYPICAL PERFORMANCE CHARACTERISTICS (Continued)



Figure 5. Typical Performance Characteristics

TYPICAL APPLICATIONS



Figure 6. Typical Applications

LM219/LM319



OUTLINE		REFER	ENCES			
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT108-1	076E06	MS-012			-97-05-22 99-12-27	

mm	10	0 51	20	1.73	0.53	0.36	19.50
	4.2	0.51	3.2	1.13	0.38	0.23	18.55

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFERENCES					
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1550E DATE	
SOT27-1	050G04	MO-001	SC-501-14			-95-03-11 99-12-27	

Dual voltage comparator

DIP14: plastic dual in-line package; 14 leads (300 mil)



SOT27-1

LM219/LM319

Product data

LM219/LM319

NOTES

LM219/LM319

Data sheet status

Data sheet status ^[1]	Product status ^[2]	Definitions
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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